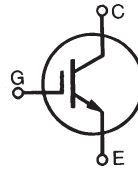


# High Voltage IGBT

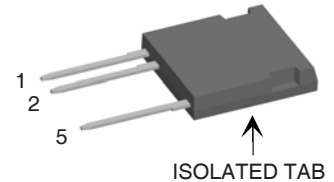
# IXGF32N170

( Electrically Isolated Tab )



$V_{CES} = 1700V$   
 $I_{C110} = 19A$   
 $V_{CE(sat)} \leq 3.5V$   
 $t_{fi(typ)} = 250ns$

ISOPLUS i4-Pak™



1 = Gate  
2 = Emitter  
5 = Collector

| Symbol         | Test Conditions  | Maximum Ratings       |            |
|----------------|--|-----------------------|------------|
| $V_{CES}$      | $T_J = 25^\circ C$ to $150^\circ C$  | 1700                  | V          |
| $V_{GES}$      | Continuous   | $\pm 20$              | V          |
| $V_{GEM}$      | Transient  | $\pm 30$              | V          |
| $I_{C25}$      | $T_C = 25^\circ C$   | 44                    | A          |
| $I_{C110}$     | $T_C = 110^\circ C$  | 19                    | A          |
| $I_{CM}$       | $T_C = 25^\circ C$ , 1ms   | 200                   | A          |
| <b>SSOA</b>    | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ C$ , $R_G = 2.7\Omega$                | $I_{CM} = 70$         | A          |
| <b>(RBSOA)</b> | Clamped Inductive Load   | @ $0.8 \cdot V_{CES}$ |            |
| $t_{sc}$       | $T_C = 125^\circ C$ , $V_{CE} = 1200V$ , $V_{GE} = 15V$ , $R_G = 10\Omega$ | 10                    | $\mu s$    |
| $P_C$          | $T_C = 25^\circ C$   | 200                   | W          |
| $T_J$          |  | -55 ... +150          | $^\circ C$ |
| $T_{JM}$       |  | 150                   | $^\circ C$ |
| $T_{stg}$      |  | -55 ... +150          | $^\circ C$ |
| $T_L$          | 1.6 mm (0.062 in.) from Case for 10s                                       | 300                   | $^\circ C$ |
| $T_{SOLD}$     | Plastic Body for 10s   | 260                   | $^\circ C$ |
| $F_C$          | Mounting Force   | 20..120 / 4.5..27     | Nm/lb.in.  |
| $V_{ISOL}$     | 50/60Hz, 1 minute  | 2500                  | V~         |
| <b>Weight</b>  |  | 5                     | g          |

## Features

- Electrically Isolated Tab
- High Current Handling Capability
- Rugged NPT Structure
- Molding Epoxies Meet UL 94 V-0 Flammability Classification

## Applications

- Capacitor Discharge & Pulser Circuits
- AC Motor Drives
- Uninterruptible Power Supplies (UPS)
- Switched-Mode and Resonant-Mode Power Supplies

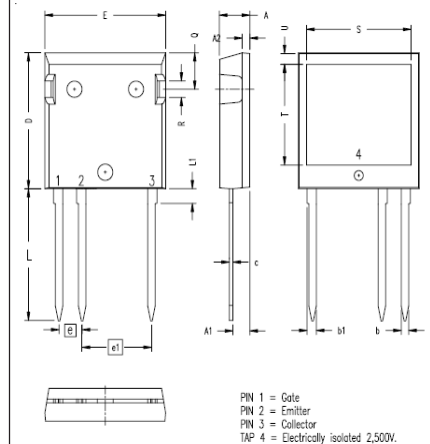
## Advantages

- High Power Density
- Suitable for Surface Mounting

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified)        | Characteristic Values |      |                    |
|---------------|--|-----------------------|------|--------------------|
|               |  | Min.                  | Typ. | Max.               |
| $BV_{CES}$    | $I_C = 1mA$ , $V_{GE} = 0V$  | 1700                  |      | V                  |
| $V_{GE(th)}$  | $I_C = 250\mu A$ , $V_{CE} = V_{GE}$   | 3.0                   |      | 5.0 V              |
| $I_{CES}$     | $V_{CE} = 0.8 \cdot V_{CES}$ , $V_{GE} = 0V$ , Note 2<br>$T_J = 125^\circ C$ |                       |      | 50 $\mu A$<br>1 mA |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$   |                       |      | $\pm 100$ nA       |
| $V_{CE(sat)}$ | $I_C = 32A$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 125^\circ C$                 | 2.7<br>3.3            | 3.5  | V<br>V             |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)   | Characteristic Values |      |                    |
|--------------|---|-----------------------|------|--------------------|
|              |   | Min.                  | Typ. | Max.               |
| $g_{fs}$     | $I_C = 32\text{A}$ , $V_{CE} = 10\text{V}$ , Note 1   | 20                    | 30   | S                  |
| $C_{ies}$    | $V_{CE} = 25\text{V}$ , $V_{GE} = 0\text{V}$ , $f = 1\text{MHz}$  |                       | 4290 | pF                 |
| $C_{oes}$    |   |                       | 167  | pF                 |
| $C_{res}$    |   |                       | 47   | pF                 |
| $Q_g$        | $I_C = 32\text{A}$ , $V_{GE} = 15\text{V}$ , $V_{CE} = 0.5 \cdot V_{CES}$   |                       | 146  | nC                 |
| $Q_{ge}$     |   |                       | 28   | nC                 |
| $Q_{gc}$     |   |                       | 52   | nC                 |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 32\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 0.6 \cdot V_{CES}$ , $R_G = 2.7\Omega$  |                       | 45   | ns                 |
| $t_{ri}$     |   |                       | 38   | ns                 |
| $t_{d(off)}$ |   |                       | 270  | 500 ns             |
| $t_{fi}$     |   |                       | 250  | 500 ns             |
| $E_{off}$    |   |                       | 10.6 | 20 mJ              |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = 32\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 0.6 \cdot V_{CES}$ , $R_G = 2.7\Omega$ |                       | 48   | ns                 |
| $t_{ri}$     |   |                       | 42   | ns                 |
| $E_{off}$    |   |                       | 6.0  | mJ                 |
| $t_{d(off)}$ |   |                       | 360  | ns                 |
| $t_{fi}$     |   |                       | 560  | ns                 |
| $E_{off}$    |   | 13.5                  | mJ   |                    |
| $R_{thJC}$   |   |                       | 0.62 | $^\circ\text{C/W}$ |
| $R_{thCS}$   |   | 0.15                  |      | $^\circ\text{C/W}$ |
| $R_{thJA}$   |   | 30                    |      | $^\circ\text{C/W}$ |

### ISOPLUS i4-Pak™ (HV) (IXGF) Outline



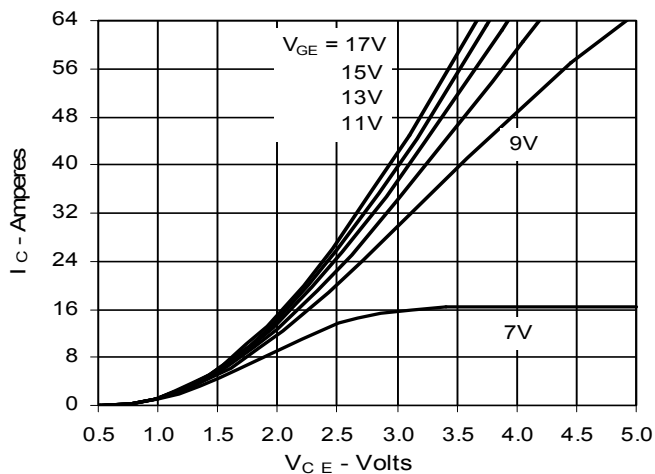
| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .190     | .205 | 4.83        | 5.21  |
| A1  | .102     | .118 | 2.59        | 3.00  |
| A2  | .046     | .085 | 1.17        | 2.16  |
| b   | .045     | .055 | 1.14        | 1.40  |
| b1  | .058     | .068 | 1.47        | 1.73  |
| C   | .020     | .029 | 0.51        | 0.74  |
| D   | .819     | .840 | 20.80       | 21.34 |
| E   | .770     | .799 | 19.56       | 20.29 |
| e   | .150 BSC |      | 3.81 BSC    |       |
| e1  | .450 BSC |      | 11.43 BSC   |       |
| L   | .780     | .840 | 19.81       | 21.34 |
| L1  | .083     | .102 | 2.11        | 2.59  |
| Q   | .210     | .244 | 5.33        | 6.20  |
| R   | .100     | .180 | 2.54        | 4.57  |
| S   | .660     | .690 | 16.76       | 17.53 |
| T   | .590     | .620 | 14.99       | 15.75 |
| U   | .065     | .080 | 1.65        | 2.03  |

- Notes: 1. Pulse test,  $t < 300\mu\text{s}$ ; duty cycle,  $d < 2\%$ .  
2. Device must be heatsunk for high temperature leakage current measurements to avoid thermal runaway.

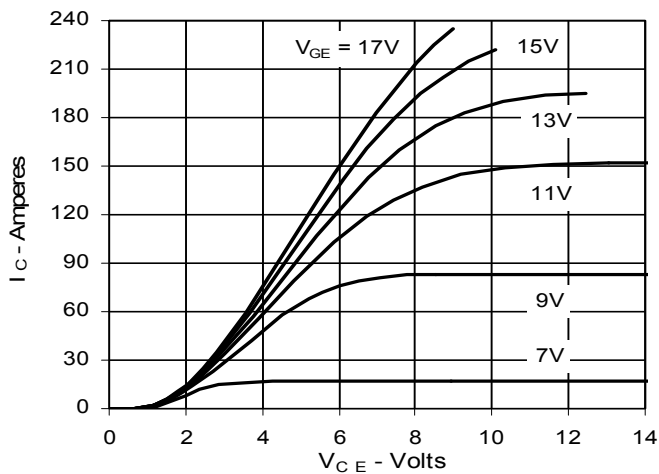
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

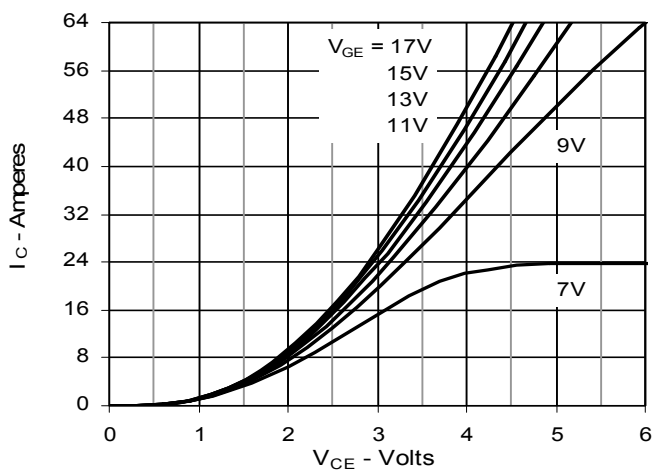
**Fig. 1. Output Characteristics @ 25°C**



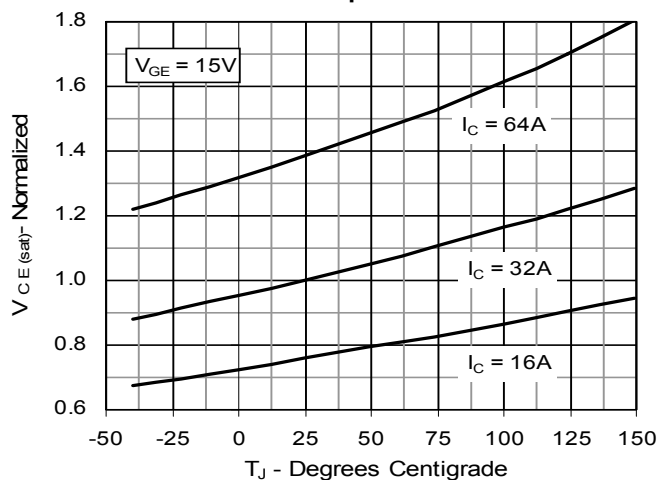
**Fig. 2. Extended Output Characteristics @ 25°C**



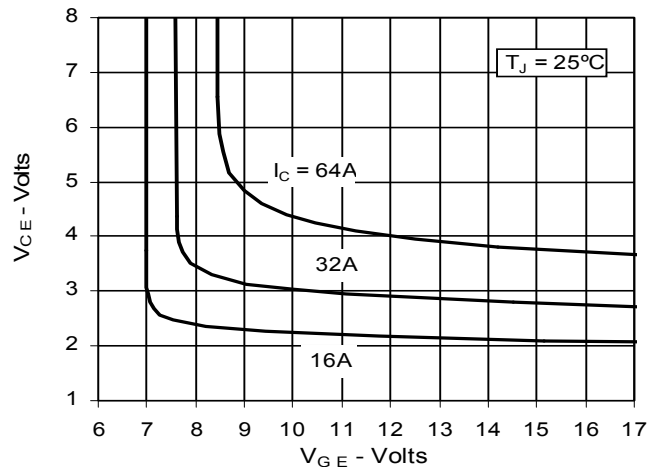
**Fig. 3. Output Characteristics @ 125°C**



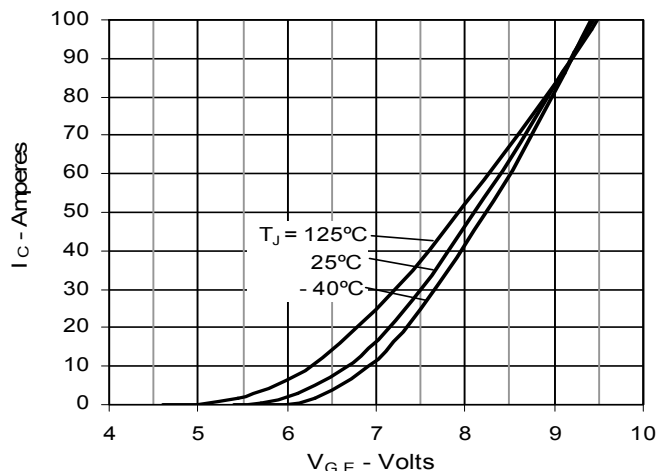
**Fig. 4. Dependence of  $V_{CE(sat)}$  on Temperature**



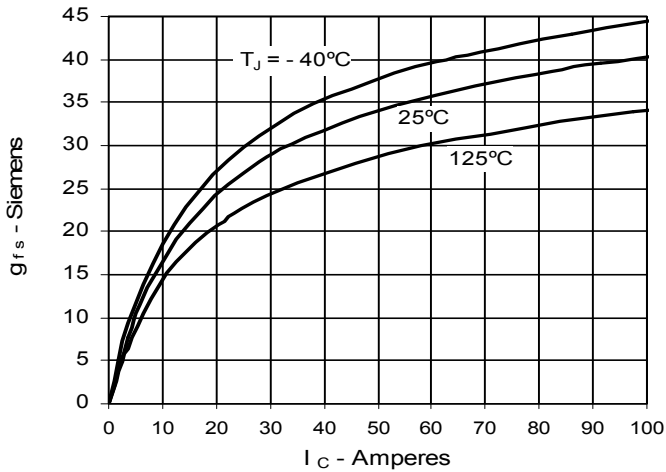
**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage**



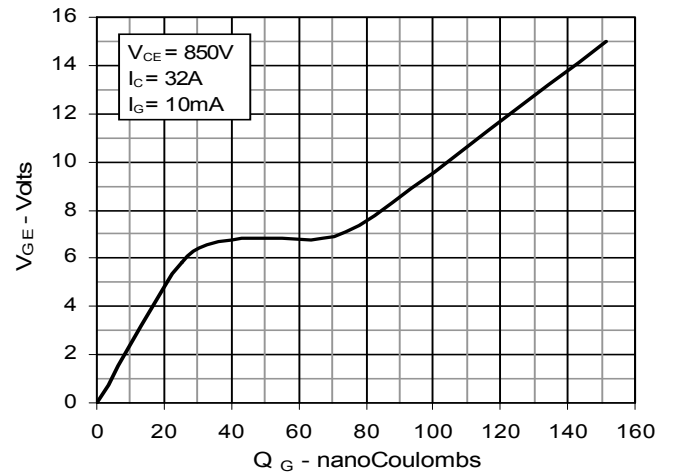
**Fig. 6. Input Admittance**



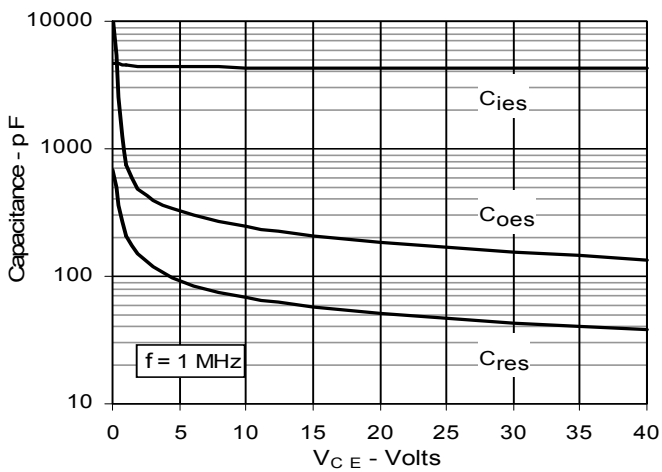
**Fig. 7. Transconductance**



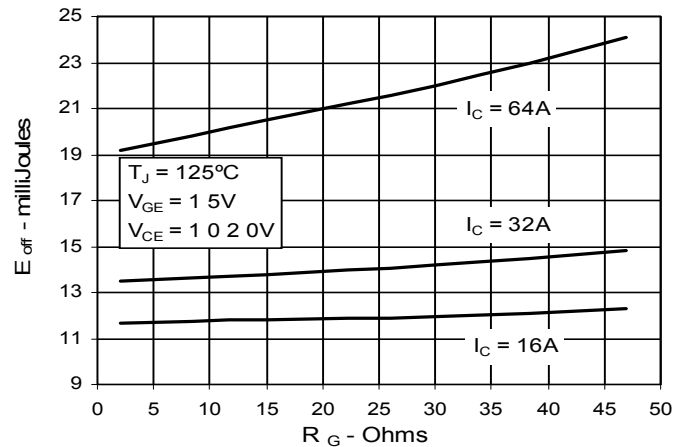
**Fig. 8. Gate Charge**



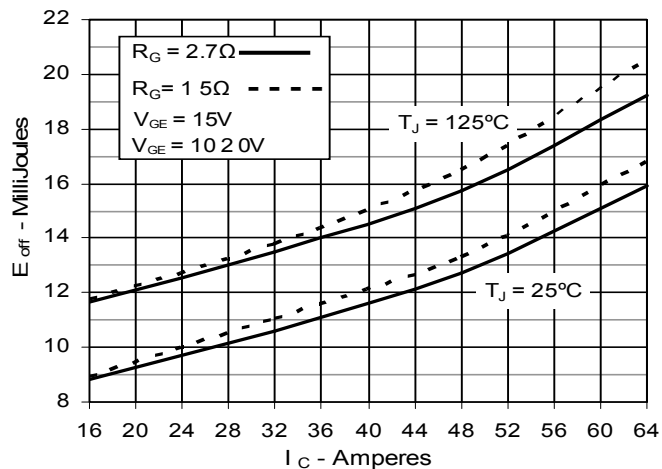
**Fig. 9. Capacitance**



**Fig. 10. Dependence of  $E_{off}$  on  $R_G$**



**Fig. 11. Dependence of  $E_{off}$  on  $I_C$**



**Fig. 12. Dependence of  $E_{off}$  on Temperature**

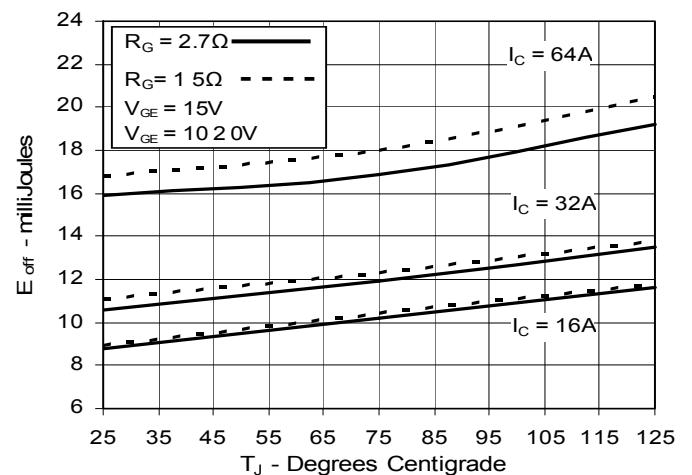


Fig. 13. Maximum Transient Thermal Impedance

